

FEATURES

- Available in the Texas Instruments NanoStar[™] and NanoFree[™] Packages
- Supports 5-V V_{CC} Operation
- Inputs Accept Voltages to 5.5 V
- Max t_{nd} of 4.9 ns at 3.3 V
- Low Power Consumption, 10-µA Max Icc
- ±24-mA Output Drive at 3.3 V
- Ioff Supports Partial-Power-Down Mode Operation

- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- **ESD Protection Exceeds JESD 22**
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

	DCT PACKAGE (TOP VIEW)		D	OCU PACKAG (TOP VIEW)	E	-	YZP PACKAGE TTOM VIEW)
A	1 8 2 7 3 6 4 5	⊥ V _{CC}	A Ⅲ	1 8	□ V _{CC}	GND	0450 Y2
B		⊥ Y0	В Ⅲ	2 7	□ Y0	Y3	0360 Y1
Y3		⊥ Y1	Y3 Ⅲ	3 6	□ Y1	B	0270 Y0
GND		⊥ Y2	GND Ⅲ	4 5	□ Y2	A	0180 V _{CC}

See mechanical drawings for dimensions.

DESCRIPTION/ORDERING INFORMATION

This 2-to-4 line decoder is designed for 1.65-V to 5.5-V V_{CC} operation.

The SN74LVC1G139 2-line to 4-line decoder is designed to be used in high-performance memory-decoding or data-routing applications requiring very short propagation delay times. In high-performance memory systems, this decoder can be used to minimize the effects of system decoding. When used with high-speed memories utilizing a fast enable circuit, the delay times of these decoders and the enable time of the memory usually are less than the typical access time of the memory. This means that the effective system delay introduced by the decoder is negligible.

ORDERING INFORMATION

T _A	PACKAGE ⁽¹⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING ⁽²⁾
	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YEP	Reel of 3000	SN74LVC1G139YEPR	<u> </u>
	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel of 5000	SN74LVC1G139YZPR	C9_
–40°C to 85°C	SSOP – DCT	Reel of 3000	SN74LVC1G139DCTR	C39
	330F - DC1	Reel of 250	SN74LVC1G139DCTT	0.39
	VSSOP – DCU	Reel of 3000	SN74LVC1G139DCUR	C39
	V330F - DC0	Reel of 250	SN74LVC1G139DCUT	0.39_

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

(2)DCT: The actual top-side marking has three additional characters that designate the year, month, and assembly/test site. DCU: The actual top-side marking has one additional character that designates the assembly/test site. YEP/YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. NanoStar, NanoFree are trademarks of Texas Instruments.

A

SN74LVC1G139 2-TO-4 LINE DECODER

TEXAS STRUMENTS www.ti.com

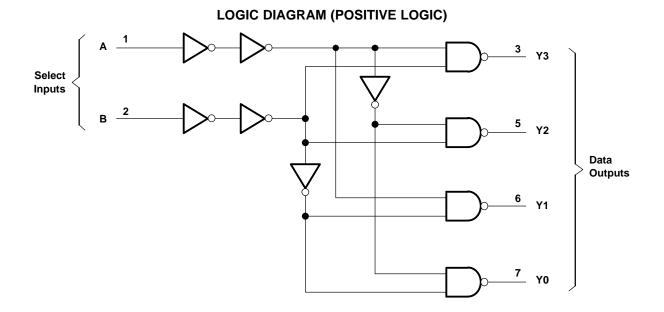
SCES602B-AUGUST 2004-REVISED DECEMBER 2005

DESCRIPTION/ORDERING INFORMATION (CONTINUED)

NanoStar[™] and NanoFree[™] package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

	FUNCTION TABLE						
SELECT	INPUTS		OUT	PUTS			
В	Α	Y0	Y1	Y2	Y3		
L	L	L	Н	Н	Н		
L	Н	Н	L	Н	Н		
н	L	н	Н	L	Н		
н	Н	н	Н	Н	L		



Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	6.5	V
VI	Input voltage range			6.5	V
Vo	Voltage range applied to any output in the high-impedance or power-off state ⁽²⁾			6.5	V
Vo	Voltage range applied to any output in the high or low state ⁽²⁾⁽³⁾			V _{CC} + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V ₀ < 0		-50	mA
I _O	Continuous output current			±50	mA
I _{cc}	Continuous current through V_{CC} or GND			±100	mA
		DCT package		220	
θ_{JA} Package thermal impedance ⁽⁴⁾		DCU package		227	°C/W
		YEP/YZP package		102	
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The value of V_{CC} is provided in the recommended operating conditions table.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.

SN74LVC1G139 2-TO-4 LINE DECODER

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Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT
V	Supply voltogo	Operating	1.65	5.5	V
V _{CC}	Supply voltage	Data retention only	1.5		v
		$V_{CC} = 1.65 \text{ V} \text{ to } 1.95 \text{ V}$	$0.65 imes V_{CC}$		
V	Ligh lovel input veltage	V_{CC} = 2.3 V to 2.7 V	1.7		V
V _{IH}	High-level input voltage	V_{CC} = 3 V to 3.6 V	2		v
		V_{CC} = 4.5 V to 5.5 V	$0.7 imes V_{CC}$		
		V_{CC} = 1.65 V to 1.95 V		$0.35 \times V_{CC}$	
V	Low-level input voltage	V_{CC} = 2.3 V to 2.7 V		0.7	V
V _{IL}		V_{CC} = 3 V to 3.6 V		0.8	v
		V_{CC} = 4.5 V to 5.5 V		$0.3 \times V_{\text{CC}}$	
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	V _{CC}	V
		$V_{CC} = 1.65 V$		-4	
		$V_{CC} = 2.3 V$		-8	
I _{OH}	High-level output current	$V_{CC} = 3 V$		-16	mA
		$v_{CC} = 3 v$		-24	
		$V_{CC} = 4.5 V$		-32	
		$V_{CC} = 1.65 V$		4	
		$V_{CC} = 2.3 V$		8	
I _{OL}	Low-level output current	$V_{CC} = 3 V$		16	mA
		V _{CC} = 3 V		24	
		$V_{CC} = 4.5 V$		32	
		V_{CC} = 1.8 V \pm 0.15 V, 2.5 V \pm 0.2 V		20	
$\Delta t/\Delta v$	Input transition rise or fall rate	$V_{CC}=3.3~V\pm0.3~V$		15	ns/V
		$V_{CC} = 5~V \pm 0.5~V$		10	
T _A	Operating free-air temperature		-40	85	°C

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP ⁽¹⁾	МАХ	UNIT	
	I _{OH} = -100 μA	1.65 V to 5.5 V	V _{CC} – 0.1				
$I_{OH} = -4 \text{ mA}$		1.65 V	1.2				
N/	$I_{OH} = -8 \text{ mA}$	2.3 V	1.9			V	
V _{OH}	I _{OH} = -16 mA	3 V	2.4			v	
	$I_{OH} = -24 \text{ mA}$	3 V	2.3				
	I _{OH} = -32 mA	4.5 V	3.8				
	I _{OL} = 100 μA	1.65 V to 5.5 V			0.1		
	I _{OL} = 4 mA	1.65 V			0.45		
N/	I _{OL} = 8 mA	2.3 V			0.3		
V _{OL}	I _{OL} = 16 mA	3 V			0.4	V	
	I _{OL} = 24 mA	3 V	0.55				
	I _{OL} = 32 mA	4.5 V			0.55		
II A or B inputs	$V_1 = 5.5 \text{ V or GND}$	0 to 5.5 V			±1	μA	
l _{off}	$V_1 \text{ or } V_0 = 5.5 \text{ V}$	0			±5	μA	
I _{CC}	$V_{\rm I} = 5.5 \text{ V or GND}, \qquad I_{\rm O} = 0$	1.65 V to 5.5 V			10	μA	
ΔI_{CC}	One input at V_{CC} – 0.6 V, Other inputs at V_{CC} or GNI	O 3 V to 5.5 V			500	μA	
Ci	$V_{I} = V_{CC} \text{ or } GND$	3.3 V		4		pF	

(1) All typical values are at V_{CC} = 3.3 V, $T_A = 25^{\circ}C$.

Switching Characteristics

over recommended operating free-air temperature range, $C_L = 15 \text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = ± 0.1	1.8 V 15 V	V _{CC} = ± 0.		V _{CC} = ± 0.		V _{CC} = ± 0.		UNIT
		(001901)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A or B	Y	2.7	15.3	1.5	7.5	0.9	4.9	0.8	3.6	ns

Switching Characteristics

over recommended operating free-air temperature range, $C_L = 30 \text{ pF}$ or 50 pF (unless otherwise noted) (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)		V_{CC} = 1.8 V ± 0.15 V		$\begin{array}{c} \mathrm{V_{CC}} \texttt{=} \texttt{2.5 V} \\ \pm \texttt{0.2 V} \end{array}$		V_{CC} = 3.3 V \pm 0.3 V		= 5 V 5 V	UNIT
		(001901)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A or B	Y	3	16.7	1.6	8.2	1.2	5.9	1.1	4.2	ns

Operating Characteristics

 $T_A = 25^{\circ}C$

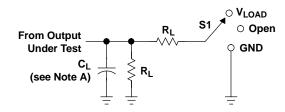
PARAMETER	TEST CONDITIONS	V _{CC} = 1.8 V TYP	V _{CC} = 2.5 V TYP	V _{CC} = 3.3 V TYP	V _{CC} = 5 V TYP	UNIT
C _{pd} ⁽¹⁾ Power dissipation capacitance	f = 10 MHz	31	34	36	39	pF

(1) Two outputs switching



VI

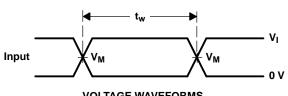
PARAMETER MEASUREMENT INFORMATION



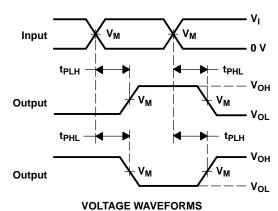
LOAD CIRCUIT

TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	V _{LOAD}
t _{PHZ} /t _{PZH}	GND

, v	INF	PUTS	N	V	•		N
V _{CC}	vı	t _r /t _f	VM	V _{LOAD}	CL	RL	V_{Δ}
$1.8~V\pm0.15~V$	v _{cc}	≤2 ns	V _{CC} /2	$2 \times V_{CC}$	15 pF	1 MΩ	0.15 V
$\textbf{2.5 V} \pm \textbf{0.2 V}$	V _{CC}	≤2 ns	V _{CC} /2	$2 \times V_{CC}$	15 pF	1 MΩ	0.15 V
3.3 V \pm 0.3 V	3 V	≤2.5 ns	1.5 V	6 V	15 pF	1 MΩ	0.3 V
5 V \pm 0.5 V	V _{CC}	≤2.5 ns	V _{CC} /2	$2 \times V_{CC}$	15 pF	1 Μ Ω	0.3 V

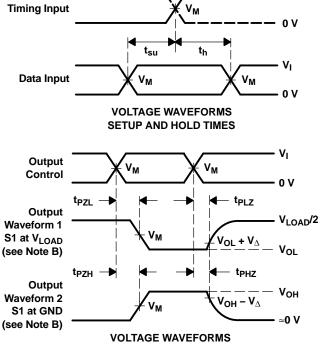


VOLTAGE WAVEFORMS PULSE DURATION



PROPAGATION DELAY TIMES

INVERTING AND NONINVERTING OUTPUTS



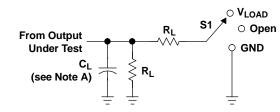
ENABLE AND DISABLE TIMES LOW- AND HIGH-LEVEL ENABLING

NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_0 = 50 Ω .
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

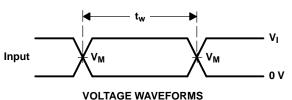
PARAMETER MEASUREMENT INFORMATION



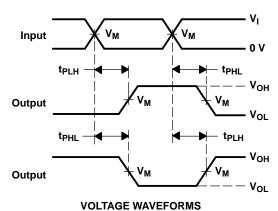
LOAD CIRCUIT

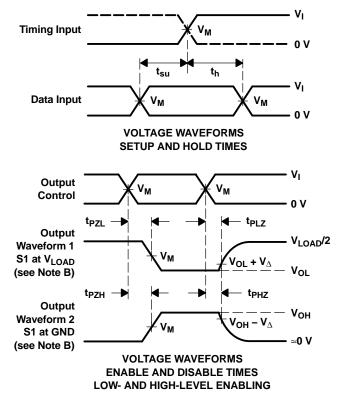
TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	V _{LOAD}
t _{PHZ} /t _{PZH}	GND

	INPUTS			N.	•	_	
V _{CC}	VI	t _r /t _f	VM	V _{LOAD}	C∟	RL	V_Δ
$1.8~V\pm0.15~V$	v _{cc}	≤2 ns	V _{CC} /2	$2 \times V_{CC}$	30 pF	1 k Ω	0.15 V
$\textbf{2.5 V} \pm \textbf{0.2 V}$	V _{CC}	≤2 ns	V _{CC} /2	$2 \times V_{CC}$	30 pF	500 Ω	0.15 V
3.3 V \pm 0.3 V	3 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
5 V \pm 0.5 V	V _{CC}	≤2.5 ns	V _{CC} /2	$2 \times V_{CC}$	50 pF	500 Ω	0.3 V



OLTAGE WAVEFORMS PULSE DURATION





PROPAGATION DELAY TIMES INVERTING AND NONINVERTING OUTPUTS

- NOTES: A. $C_{\mbox{L}}$ includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_{O} = 50 Ω .
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en} .
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .
 - H. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit and Voltage Waveforms

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
74LVC1G139DCTRE4	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74LVC1G139DCTRG4	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74LVC1G139DCTTE4	ACTIVE	SM8	DCT	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74LVC1G139DCURE4	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74LVC1G139DCURG4	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74LVC1G139DCUTE4	ACTIVE	US8	DCU	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74LVC1G139DCUTG4	ACTIVE	US8	DCU	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G139DCTR	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G139DCTT	ACTIVE	SM8	DCT	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G139DCUR	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G139DCUT	ACTIVE	US8	DCU	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC1G139YZPR	ACTIVE	DSBGA	YZP	8	3000	TBD	Call TI	Call TI

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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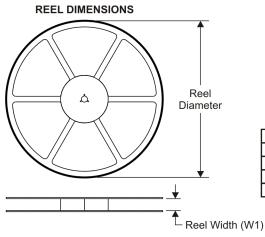
PACKAGE OPTION ADDENDUM



27-Nov-2008

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC1G139DCUR	US8	DCU	8	3000	180.0	9.2	2.25	3.35	1.05	4.0	8.0	Q3



PACKAGE MATERIALS INFORMATION

26-Nov-2008



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC1G139DCUR	US8	DCU	8	3000	202.0	201.0	28.0

DCU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

D. Falls within JEDEC MO-187 variation CA.



MECHANICAL DATA

MPDS049B - MAY 1999 - REVISED OCTOBER 2002

DCT (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

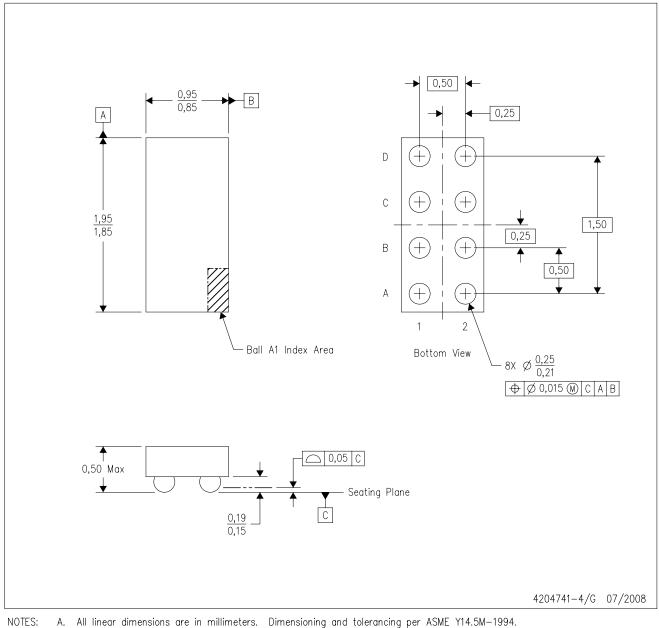
C. Body dimensions do not include mold flash or protrusion

D. Falls within JEDEC MO-187 variation DA.



YZP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY



- B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.
- D. This package is lead-free. Refer to the 8 YEP package (drawing 4204725) for tin-lead (SnPb).

NanoFree is a trademark of Texas Instruments.



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